### INTEGRATED CIRCUITS

# DATA SHEET

**74LVT16244B**3.3V LVT 16-bit buffer/driver (3-State)

Prooduct specification Supersedes data of 1998 Feb 19 IC23 Data Handbook







### 3.3V 16-bit buffer/driver (3-State)

### 74LVT16244B

#### **FEATURES**

- 16-bit bus interface
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

#### **DESCRIPTION**

The 74LVT16244B is a high-performance BiCMOS product designed for  $V_{CC}$  operation at 3.3V.

This device is a 16-bit buffer and line driver featuring non-inverting 3-State bus outputs. The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer.

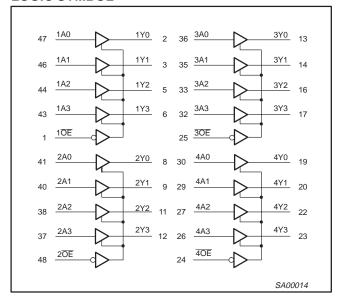
#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS T <sub>amb</sub> = 25°C	TYPICAL	UNIT
<sup>t</sup> PLH <sup>t</sup> PHL	Propagation delay nAx to nYx	$C_L = 50$ pF; $V_{CC} = 3.3$ V	1.8	ns
C <sub>IN</sub>	Input capacitance nOE	V <sub>I</sub> = 0V or 3.0V	3	pF
C <sub>OUT</sub>	Output capacitance	Outputs disabled; V <sub>O</sub> = 0V or 3.0V	9	pF
I <sub>CCZ</sub>	Total supply current	Outputs disabled; V <sub>CC</sub> = 3.6V	70	μΑ

#### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	-40°C to +85°C	74LVT16244B DL	VT16244B DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74LVT16244B DGG	VT16244B DGG	SOT362-1

#### **LOGIC SYMBOL**

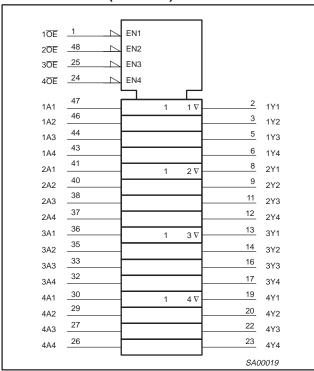


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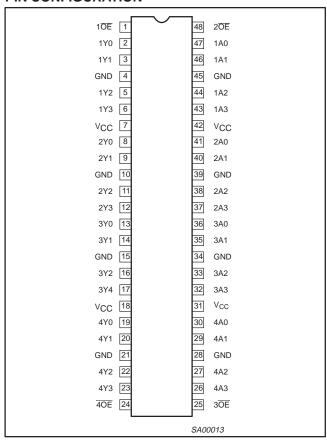
### 3.3V 16-bit buffer/driver (3-State)

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#### LOGIC SYMBOL (IEEE/IEC)



#### **PIN CONFIGURATION**



#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
47, 46, 44, 43 41, 40, 38, 37 36, 35, 33, 32 30, 29, 27, 26	1A0 - 1A3, 2A0 - 2A3, 3A0 - 3A3, 4A0 - 4A3	Data inputs
2, 3, 5, 6 8, 9, 11, 12 13, 14, 16, 17 19, 20, 22, 23	1Y0 - 1Y3, 2Y0 - 2Y3, 3Y0 - 3Y3, 4Y0 - 4Y3	Data outputs
1, 48 25, 24	1 <u>OE</u> , 2 <u>OE</u> , 3 <u>OE</u> , 4 <u>OE</u>	Output enables
4, 10, 15, 21 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V <sub>CC</sub>	Positive supply voltage

#### **FUNCTION TABLE**

INP	JTS	OUTPUTS
nOE	nAx	nYx
L	L	L
L	Н	Н
Н	X	Z

H = High voltage level

= Low voltage level

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X = Don't care Z = High Impedance "off" state

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#### **ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>**

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +4.6	V
I <sub>IK</sub>	DC input diode current	V <sub>I</sub> < 0	-50	mA
V <sub>I</sub>	DC input voltage <sup>3</sup>		-0.5 to +7.0	V
lok	DC output diode current	V <sub>O</sub> < 0	-50	mA
V <sub>OUT</sub>	DC output voltage <sup>3</sup>	Output in Off or High state	-0.5 to +7.0	V
	DC quitaut quiriant	Output in Low state	128	A
IOUT	DC output current	Output in High state	-64	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C

#### NOTES:

Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the
device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to
absolute-maximum-rated conditions for extended periods may affect device reliability.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

#### **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	LIM	LIMITS			
STWIBUL	PARAMETER	MIN	MAX	UNIT		
V <sub>CC</sub>	DC supply voltage	2.7	3.6	V		
VI	Input voltage	0	5.5	V		
V <sub>IH</sub>	High-level input voltage	2.0		V		
V <sub>IL</sub>	Input voltage		0.8	V		
I <sub>OH</sub>	High-level output current		-32	mA		
	Low-level output current		32	A		
loL	Low-level output current; current duty cycle ≤ 50%; f ≥ 1kHz		64	mA		
Δt/Δν	Input transition rise or fall rate; Outputs enabled		10	ns/V		
T <sub>amb</sub>	Operating free-air temperature range	-40	+85	°C		

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

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#### DC ELECTRICAL CHARACTERISTICS

					LIMITS		
SYMBOL	PARAMETER	TEST CONDITIONS		Temp =	-40°C to	+85°C	UNIT
			MIN	TYP <sup>1</sup>	MAX		
$V_{IK}$	Input clamp voltage	$V_{CC} = 2.7V; I_{IK} = -18mA$			-0.85	-1.2	V
		$V_{CC} = 2.7 \text{ to } 3.6 \text{V}; I_{OH} = -100 \mu\text{A}$		V <sub>CC</sub> -0.2	V <sub>CC</sub>		
$V_{OH}$	High-level output voltage	$V_{CC} = 2.7V; I_{OH} = -8mA$		2.4	2.5		V
		$V_{CC} = 3.0V; I_{OH} = -32mA$		2.0	2.3		
		$V_{CC} = 2.7V; I_{OL} = 100\mu A$			0.07	0.2	
		V <sub>CC</sub> = 2.7V; I <sub>OL</sub> = 24mA			0.3	0.5	
$V_{OL}$	Low-level output voltage	V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 16mA			0.25	0.4	V
		$V_{CC} = 3.0V; I_{OL} = 32mA$			0.3	0.5	
		V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 64mA			0.4	0.55	
		$V_{CC} = 3.6V$ ; $V_I = V_{CC}$ or GND	Control pins		0.1	±1.0	
	Innut looks as surrent	$V_{CC} = 0 \text{ or } 3.6V; V_I = 5.5V$			0.4	10	
tı	Input leakage current	$V_{CC} = 3.6V; V_{I} = V_{CC}$	Data nine4		0.1	1	μΑ
		$V_{CC} = 3.6V; V_I = 0$	Data pins <sup>4</sup>		-0.4	-5	
I <sub>OFF</sub>	Output off current	$V_{CC} = 0V$ ; $V_{I}$ or $V_{O} = 0$ to 4.5V			0.1	±100	μΑ
		$V_{CC} = 3V; V_I = 0.8V$		75	135		
I <sub>HOLD</sub>	Bus Hold current A inputs <sup>6</sup>	$V_{CC} = 3V; V_I = 2.0V$		-75	-135		μΑ
		$V_{CC} = 0V \text{ to } 3.6V; V_{CC} = 3.6V$		±500			
I <sub>EX</sub>	Current into an output in the High state when V <sub>O</sub> > V <sub>CC</sub>	$V_{O} = 5.5V; V_{CC} = 3.0V$			50	125	μА
I <sub>PU/PD</sub>	Power up/down 3-State output current <sup>3</sup>	$V_{CC} \le 1.2V$ ; $V_O = 0.5V$ to $V_{CC}$ ; $V_I = GND$ $OE/\overline{OE} = Don't$ care	or V <sub>CC</sub>		1	±100	μА
l <sub>ozh</sub>	3-State output High current	$V_{CC} = 3.6V; V_{O} = 3.0V; V_{I} = V_{IL} \text{ or } V_{IH}$			0.5	5	μΑ
I <sub>OZL</sub>	3-State output Low current	$V_{CC} = 3.6V; V_{O} = 0.5V; V_{I} = V_{IL} \text{ or } V_{IH}$			0.5	-5	μΑ
Іссн		$V_{CC} = 3.6V$ ; Outputs High, $V_I = GND$ or $V_{CC} = 0.00$	/ <sub>CC,</sub> I <sub>O =</sub> 0		0.07	0.12	
I <sub>CCL</sub>	Quiescent supply current	$V_{CC} = 3.6V$ ; Outputs Low, $V_I = GND$ or $V$	CC, I <sub>O =</sub> 0		4.0	6.0	mΑ
I <sub>CCZ</sub>		$V_{CC} = 3.6V$ ; Outputs Disabled; $V_I = GND$	or $V_{CC}$ , $I_{O} = 0^5$		0.07	0.12	
$\Delta I_{CC}$	Additional supply current per input pin <sup>2</sup>	$V_{CC}$ = 3V to 3.6V; One input at $V_{CC}$ -0.6V Other inputs at $V_{CC}$ or GND	,		0.1	0.2	mA

- All typical values are at V<sub>CC</sub> = 3.3V and T<sub>amb</sub> = 25°C.
   This is the increase in supply current for each input at the specified voltage level other than V<sub>CC</sub> or GND
   This parameter is valid for any V<sub>CC</sub> between 0V and 1.2V with a transition time of up to 10msec. From V<sub>CC</sub> = 1.2V to V<sub>CC</sub> = 3.3V ± 0.3V a transition time of 100µsec is permitted. This parameter is valid for T<sub>amb</sub> = 25°C only.
   Unused pins at V<sub>CC</sub> or GND.
   I<sub>CCZ</sub> is measured with outputs pulled to V<sub>CC</sub> or GND.

- 6. This is the bus hold overdrive current required to force the input to the opposite logic state.

#### **AC CHARACTERISTICS**

GND = 0V;  $t_R = t_F = 2.5 \text{ns}$ ;  $C_L = 50 \text{pF}$ ;  $R_L = 500 \Omega$ ;  $T_{amb} = -40 ^{\circ} \text{C}$  to  $+85 ^{\circ} \text{C}$ .

SYMBOL PARAMETER		PARAMETER WAVEFORM $V_{CC} = 3.3V \pm 0.3V$		.3V	V <sub>CC</sub> = 2.7V	UNIT	
			MIN	TYP <sup>1</sup>	MAX	MAX	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation delay nAx to nYx	1	0.5 0.5	1.8 1.7	3.2 3.2	4.0 4.0	ns
t <sub>PZH</sub> t <sub>PZL</sub>	Output enable time to High and Low level	2	1.0 1.0	2.3 2.1	4.0 4.0	5.0 5.3	ns
t <sub>PHZ</sub> t <sub>PLZ</sub>	Output disable time from High and Low Level	2	1.0 1.0	3.2 2.9	4.5 4.0	5.0 4.4	ns

1. All typical values are at  $V_{CC}$  = 3.3V and  $T_{amb}$  = 25°C.

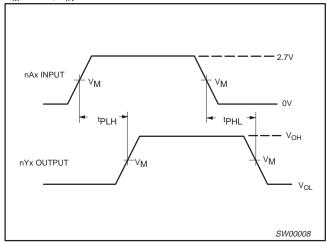
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### 3.3V 16-bit buffer/driver (3-State)

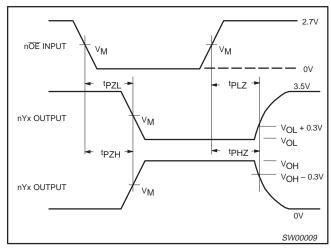
### 74LVT16244B

#### **AC WAVEFORMS**

 $V_{M} = 1.5V, V_{IN} = GND \text{ to } 3.0V$ 

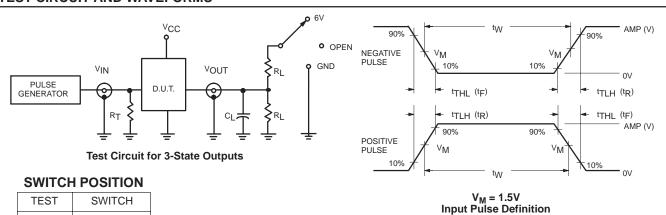


Waveform 1. Input (nAx) to Output ( $n\overline{Y}x$ ) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

#### **TEST CIRCUIT AND WAVEFORMS**



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TEST	SWITCH
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND
t <sub>PLZ</sub> /t <sub>PZL</sub>	6V
t <sub>PLH</sub> /t <sub>PHL</sub>	open

#### **DEFINITIONS**

R<sub>L</sub> = Load resistor; see AC CHARACTERISTICS for value.

 $C_L = Load$  capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

 $R_T$  = Termination resistance should be equal to  $Z_{OUT}$  of pulse generators.

FAMILY	INPUT PULSE REQUIREMENTS								
FAIVIILT	Amplitude	Rep. Rate	t <sub>W</sub>	t <sub>R</sub>	t <sub>F</sub>				
74LVT16	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns				

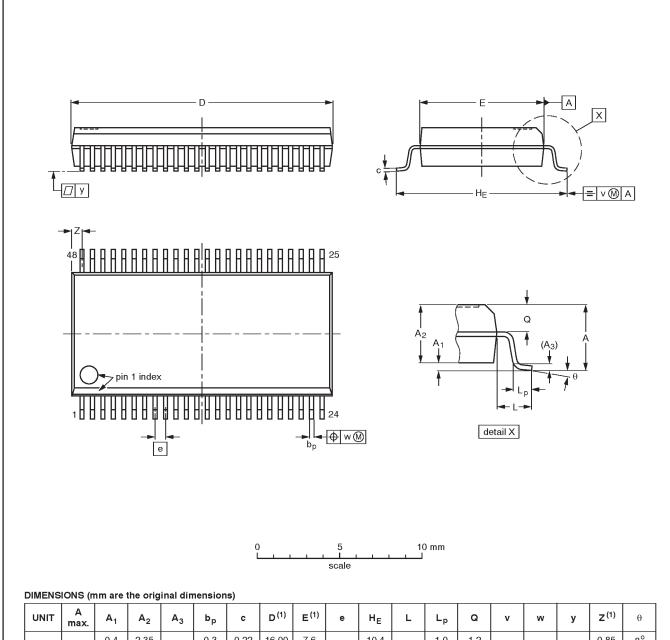
SW00003

## 3.3V LVT 16-bit buffer/driver (3-State)

### 74LVT16244B

### SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1



UN	ΝIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
m	m	2.8	0.4 0.2	2.35 2.20	0.25	0.3 0.2	0.22 0.13	16.00 15.75	7.6 7.4	0.635	10.4 10.1	1.4	1.0 0.6	1.2 1.0	0.25	0.18	0.1	0.85 0.40	8° 0°

#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

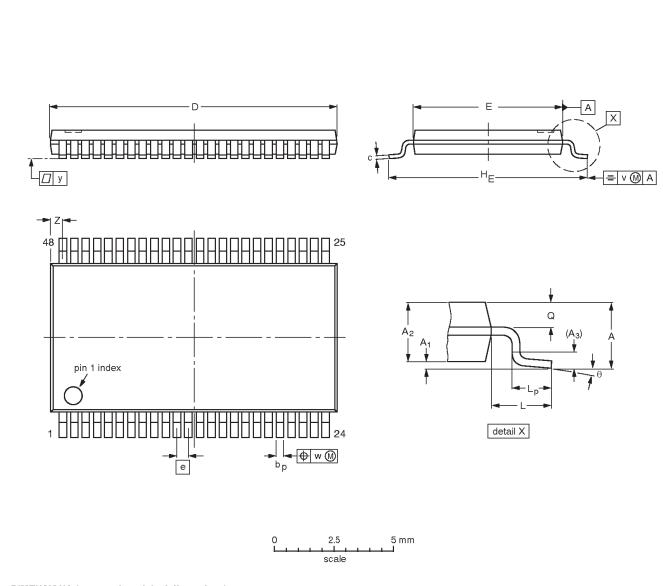
OUTLINE		REFER	RENCES		EUROPEAN	ISSUE DATE
VERSION	VERSION IEC JEDEC EIAJ				PROJECTION	ISSUE DATE
SOT370-1		MO-118AA				<del>93-11-02</del> 95-02-04

## 3.3V LVT 16-bit buffer/driver (3-State)

### 74LVT16244B

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm

SOT362-1



#### DIMENSIONS (mm are the original dimensions).

UNIT	A max.	Α1	A <sub>2</sub>	А3	bp	С	D <sup>(1)</sup>	E <sup>(2)</sup>	e	HE	L	Lp	Q	>	w	у	Z	θ
mm	1.2	0.15 0.05	1.05 0.85	0.25	0.28 0.17	0.2 0.1	12.6 12.4	6.2 6.0	0.5	8.3 7.9	1	0.8 0.4	0.50 0.35	0.25	0.08	0.1	0.8 0.4	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT362-1		MO-153ED				<del>-93-02-03-</del> 95-02-10

# 3.3V LVT 16-bit buffer/driver (3-State)

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**NOTES** 

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### 3.3V LVT 16-bit buffer/driver (3-State)

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#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make chages at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

<sup>[1]</sup> Please consult the most recently issued datasheet before initiating or completing a design.

#### **Definitions**

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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